

Data Sheet January 2000 File Number 2878.3

15A, 1000V Ultrafast Diode

The RURP15100 is an ultrafast diode with soft recovery characteristics ($t_{rr} < 100$ ns). It has a low forward voltage drop and is of silicon nitride passivated, ion-implanted, epitaxial construction.

This device is intended for use as a freewheel/clamping diode and rectifier in a variety of switching power supplies and other power switching applications. Its low stored charge and ultrafast recovery with soft recovery characteristics minimizes ringing and electrical noise in many power switching circuits, thus reducing power loss in the switching transistor.

Formerly developmental type TA09906.

Ordering Information

PART NUMBER	PACKAGE	BRAND
RURP15100	TO-220AC	RURP15100

NOTE: When ordering, use the entire part number.

Symbol



Features

Ultrafast with Soft Recovery	<100ns
Operating Temperature	175°C
Reverse Voltage	1000V

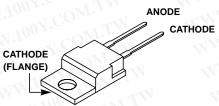
- Avalanche Energy Rated
- Planar Construction

Applications

- Switching Power Supply
- · Power Switching Circuits
- General Purpose

Packaging

JEDEC TO-220AC



Absolute Maximum Ratings	$T_C = 25^{\circ}C$, Unless Otherwise Specified

		RURP15100	UNITS
Peak Repetitive Reverse Voltage	V _{RRM}	1000	V
Working Peak Reverse Voltage	V _{RWM}	1000	V
DC Blocking Voltage	V _R	1000	V
Average Rectified Forward Current	I _{F(AV)}	15 Y.C	OM.TVA
Repetitive Peak Surge Current	I _{FRM}	30	COM-A
Nonrepetitive Peak Surge Current	I _{FSM}	200	Α
Maximum Power Dissipation	P _D	100	W
Avalanche Energy (See Figures 7 and 8)	E _{AVL}	20	mJ
Operating and Storage Temperature	Toro Ti	-65 to 175	о _С

Electrical Specifications $T_C = 25^{\circ}C$, Unless Otherwise Specified.

SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
V _F 000 C	I _F = 15A	100X. COM.	- V	1.8	COM-V
	I _F = 15A, T _C = 150 ^o C	N 100X - COM	TV -	1.5	CON
I _R	V _R = 1000V	W.1007-COL	LTW -	100	μΑ
	$V_R = 1000V, T_C = 150^{\circ}C$	M.1007.CO	M.TV	500	μΑ
Vtr 100	I _F = 1A, dI _F /dt = 100A/μs	W.1007.	OWITY	100	ns
	$I_F = 15A$, $dI_F/dt = 100A/\mu s$	WW.1007.0	OW.TW	125	ns
t _a	I _F = 15A, dI _F /dt = 100A/μs	WW.1001.	75	THE TOTAL PROPERTY.	ns
t _b	$I_F = 15A$, $dI_F/dt = 100A/\mu s$	W 100	40		ns
$R_{ heta JC}$	M.1001. COW.TW	W.100	COMITY	1.5	°C/W

DEFINITIONS

 V_F = Instantaneous forward voltage (pw = 300 μ s, D = 2%).

I_R = Instantaneous reverse current.

 t_{rr} = Reverse recovery time at dI_F/dt = 100A/ μ s (See Figure 6), summation of t_a + t_b

 t_a = Time to reach peak reverse current at dI_F/dt = 100A/ μ s (See Figure 6).

t_b = Time from peak I_{RM} to projected zero crossing of I_{RM} based on a straight line from peak I_{RM} through 25% of I_{RM} (See Figure 6).

 $R_{\theta JC}$ = Thermal resistance junction to case

pw = pulse width.

D = duty cycle.

Typical Performance Curves

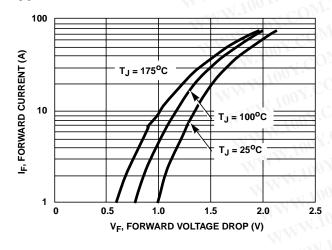


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

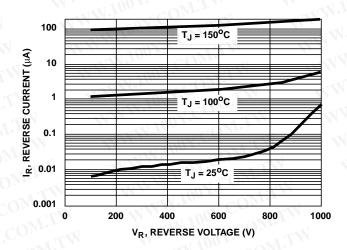


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

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RURP15100

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Typical Performance Curves (Continued)

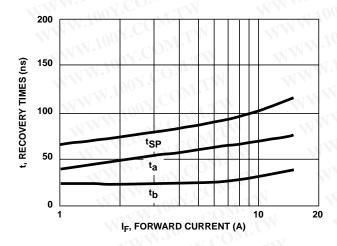


FIGURE 3. t_{rr}, t_a AND t_b CURVES vs FORWARD CURRENT

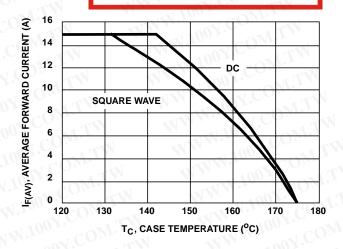


FIGURE 4. CURRENT DERATING CURVE

Test Circuits and Waveforms

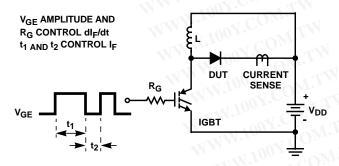


FIGURE 5. t_{rr} TEST CIRCUIT

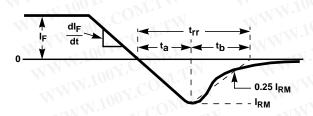


FIGURE 6. t_{rr} WAVEFORMS AND DEFINITIONS

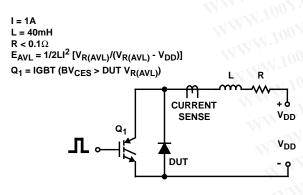


FIGURE 7. AVALANCHE ENERGY TEST CIRCUIT

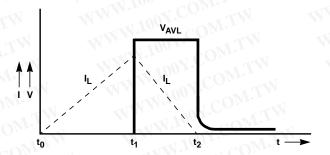


FIGURE 8. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

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